







# PARALLEL REAL-TIME CLOCK WITH CPU SUPERVISOR AND EXTERNAL SRAM NONVOLATILE MEMORY BACKUP

#### **FEATURES**

- Real-Time Clock Counts Seconds Through Centuries in BCD Format
  - bq4802Y: 5-V Operation
  - bq4802LY: 3.3-V Operation
- On-Chip Battery-Backup Switchover Circuit With Nonvolatile Control for External SRAM
- Less Than 500 nA of Clock Operation Current in Backup Mode
- Microprocessor Reset With Push-Button Override
- Independent Watchdog Timer With Programmable Time-Out Period
- Power-Fail Interrupt Warning
- Programmable Clock Alarm Interrupt Active in Battery-Backup Mode
- Programmable Periodic Interrupt
- Battery-Low Warning
- 28-pin SOIC, TSSOP, and SNAPHAT Package Options

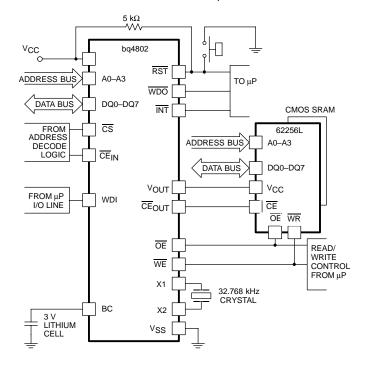
#### **APPLICATIONS**

- Telecommunications Base Stations
- Servers
- Handheld Data Collection Equipment
- Medical Equipment
- Handheld Instrumentation
- Test Equipment

#### DESCRIPTION

The bq4802Y/bq4802LY real-time clock is a low-power microprocessor peripheral that integrates a time-of-day clock, a century-based calendar, and a CPU supervisor, with package options including a 28-pin SOIC, TSSOP, or SNAPHAT that requires the bq48SH-28x6 to complete the two-piece module. The bq4802Y/bq4802LY is ideal for fax machines, copiers, industrial control systems, point-of-sale terminals, data loggers, and computers.

#### TYPICAL APPLICATION



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## **DESCRIPTION (CONTINUED)**

The bq4802Y/bq4802LY provides direct connections for a 32.768-kHz quartz crystal and a 3-V backup battery. Through the use of the conditional chip enable output ( $\overline{\text{CE}}_{\text{OUT}}$ ) and battery voltage output ( $\overline{\text{V}}_{\text{OUT}}$ ) pins, the bq4802Y/bq4802LY can write-protect and make non- volatile external SRAMs. The backup cell powers the real-time clock and maintains SRAM information in the absence of system voltage. The crystal and battery are contained within the modules for a more integrated solution.

The bq4802Y/bq4802LY contains a temperature-compensated reference and comparator circuit that monitors the status of its voltage supply. When the bq4802Y/bq4802LY detects an out-of-tolerance condition, it generates an interrupt warning and subsequently a microprocessor reset. The reset stays active for 200 ms after V<sub>CC</sub> rises within tolerance, to allow for power supply and processor stabilization. The reset function also allows for an external push-button override.

#### ORDERING INFORMATION

| _            | ODED ATION | DEVICES      |                           |                        | OVMBOL   |
|--------------|------------|--------------|---------------------------|------------------------|----------|
| IA           | OPERATION  | SOIC(1) (DW) | TSSOP <sup>(1)</sup> (PW) | SNAPHAT(1)(2)(3) (DSH) | SYMBOL   |
| 0°C to +70°C | 5 V        | bq4802YDW    | bq4802YPW                 | bq4802YDSH             | bq4802Y  |
|              | 3.3 V      | bq4802LYDW   | bq4802LYPW                | bq4802LYDSH            | bq4802LY |

- (1) The DW, PW and DSH packages are available taped and reeled. Add an R suffix to the device type (i.e., bq4802YDWR).
- (2) The DSH package is available taped only.
- (3) The bq48SH-28x6 should be ordered to complete the SNAPHAT module and is the same part number for both 3.3-V and 5-V modules.

CAUTION: Wave soldering of DSH package may cause damage to SNAPHAT sockets.

#### **ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature range unless otherwise noted(1)

|                                                                      | bq4802Y<br>bq4802LY |
|----------------------------------------------------------------------|---------------------|
| Input voltage range, VCC, V <sub>T</sub> (V <sub>T</sub> ≤ VCC +0.3) | –0.3 V to 6.0 V     |
| Operating temperature range, T <sub>J</sub>                          | 0°C to 70°C         |
| Storage temperature range, T <sub>Stg</sub>                          | −55°C to 125°C      |
| Temperature under bias, T <sub>Jbias</sub>                           | -40°C to 85°C       |
| Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds         | 300°C               |

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### RECOMMENDED OPERATING CONDITIONS

|                                                 |                                         | MIN                   | MAX                   | UNIT |
|-------------------------------------------------|-----------------------------------------|-----------------------|-----------------------|------|
| Supply voltage, V <sub>CC</sub>                 | bq4802Y                                 | 4.5                   | 5.5                   | .,   |
|                                                 | bq4802LY                                | 2.7                   | 3.6                   | V    |
| Input low voltage, VIL                          |                                         | -0.3 0.8              |                       | V    |
| Input high voltage, V <sub>IH</sub> 2.2         |                                         | V <sub>CC</sub> + 0.3 | V                     |      |
| Backup cell voltage, VBC                        | o cell voltage, V <sub>BC</sub> 2.4 4.0 |                       | V                     |      |
| Push button reset input low, V <sub>BC</sub>    |                                         | -0.3                  | 0.4                   | V    |
| Push button reset input high, V <sub>PBRH</sub> |                                         |                       | V <sub>CC</sub> + 0.3 | V    |



## **ELECTRICAL CHARACTERISTICS**

 $(T_A = 25^{\circ}C, V_{CC(min)} \le V_{CC} \le V_{CC(max)}$  unless otherwise noted)

| INPUT S            | SUPPLY                            | ,        |                                                                                                                                                       |                      |                 |      |      |
|--------------------|-----------------------------------|----------|-------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------|-----------------|------|------|
|                    | PARAMETER                         |          | TEST CONDITIONS                                                                                                                                       | MIN                  | TYP             | MAX  | UNIT |
| ICC                | Supply current                    |          | 100% Minimum duty cycle,<br>CS = V <sub>IL</sub> , I <sub>I/O</sub> = 0 mA                                                                            |                      | 5               | 9    | mA   |
|                    |                                   |          | CS = V <sub>IH</sub>                                                                                                                                  |                      | 3               |      |      |
| I <sub>SB1</sub>   | Standby supply current            |          | $\overline{\text{CS}} = V_{\text{CC}} - 0.2 \text{ V},$<br>0 V \leq V_{\text{IN}} \leq 0.2 \text{ V or V}_{\text{IN}} = V_{\text{CC}} - 0.2 \text{ V} |                      | 1.5             |      | mA   |
| ICCB               | Battery operation supply current  |          | $V_{BC} = 3 \text{ V},  T_A = 25^{\circ}\text{C},$<br>No load at $V_{OUT}$ or $\overline{\text{CE}}_{OUT}$ , $I_{I/O} = 0 \text{ mA}$                 |                      | 0.3             | 0.5  | μΑ   |
| ILI                | Input leakage current             |          | V <sub>IN</sub> = V <sub>SS</sub> to V <sub>CC</sub>                                                                                                  | -1                   |                 | 1    | μΑ   |
| ILO                | Output leakage current            |          | $\overline{CS} = V_{IH} \text{ or } \overline{OE} = V_{IH} \text{ or } \overline{WE} = V_{IL}$                                                        | -1                   |                 | 1    | μΑ   |
| VOUT(1)<br>VOUT(2) | Output voltage                    |          | $I_{OUT} = 80 \text{ mA}, V_{CC} > V_{BC}$<br>$I_{OUT} = 100 \mu\text{A},  V_{CC} < V_{BC}$                                                           | V <sub>CC</sub> -0.3 |                 |      | ٧    |
|                    |                                   | bq4802Y  |                                                                                                                                                       | 4.30                 | 4.37            | 4.5  |      |
| VPFD               | Power fail detect voltage         | bq4802LY |                                                                                                                                                       | 2.4                  | 2.53            | 2.65 | V    |
| V                  | Cumply quitab avaryaltaga         |          | V <sub>BC</sub> > V(PFD)                                                                                                                              |                      | VPFD            |      | V    |
| Vso                | Supply switch over voltage        |          | V <sub>BC</sub> < V(PFD)                                                                                                                              |                      | V <sub>BC</sub> |      | V    |
| V <sub>RST</sub>   | RST output voltage <sup>(1)</sup> |          | I(RST) = 4 mA                                                                                                                                         |                      |                 | 0.4  | V    |
| VINT               | INT output voltage <sup>(1)</sup> |          | I(INT) = 4 mA                                                                                                                                         |                      |                 | 0.4  | V    |

<sup>(1)</sup>  $\overline{RST}$  and  $\overline{INT}$  are open drain outputs.

| WATCHDOG |                                   |                 |     |     |     |      |  |  |  |
|----------|-----------------------------------|-----------------|-----|-----|-----|------|--|--|--|
|          | PARAMETER                         | TEST CONDITIONS | MIN | TYP | MAX | UNIT |  |  |  |
| I(WDIL)  | Low-level watchdog input current  |                 | -50 | -10 |     | ^    |  |  |  |
| I(WDIH)  | High-level watchdog input current |                 |     | 20  | 50  | μΑ   |  |  |  |
| V        | ISINK = 4 mA                      |                 |     |     | 0.4 |      |  |  |  |
| V(WDO)   | WDO output voltage                | ISOURCE = 2 mA  | 2.4 |     |     | V    |  |  |  |

| CRYSTAL SPECIFICATIONS (DT-26) OR EQUIVALENT) |                              |                 |        |        |        |        |  |  |  |  |
|-----------------------------------------------|------------------------------|-----------------|--------|--------|--------|--------|--|--|--|--|
|                                               | PARAMETER                    | TEST CONDITIONS | MIN    | TYP    | MAX    | UNIT   |  |  |  |  |
| fO                                            | Oscillation frequency        |                 |        | 32.768 |        | kHz    |  |  |  |  |
| CL                                            | Load capacitance             |                 |        | 6      |        | pF     |  |  |  |  |
| T <sub>P</sub>                                | Temperature turnover point   |                 | 20     | 25     | 30     | °C     |  |  |  |  |
| k                                             | Parabolic curvature constant |                 |        |        | -0.042 | ppm/°C |  |  |  |  |
| Q                                             | Quality factor               |                 | 40,000 | 70,000 |        |        |  |  |  |  |
| R <sub>1</sub>                                | Series resistance            |                 |        |        | 45     | kΩ     |  |  |  |  |
| C <sub>0</sub>                                | Shunt capacitance            |                 |        | 1.1    | 1.8    | pF     |  |  |  |  |
| C <sub>0</sub> /C <sub>1</sub>                | Capacitance ratio            |                 |        | 430    | 600    |        |  |  |  |  |
| DL                                            | Drive level                  |                 |        |        | 1      | μW     |  |  |  |  |
| $\Delta f/f_0$                                | Aging (first year at 25°C)   |                 |        | 1      | _      | ppm    |  |  |  |  |

| CAPACITANCE      |                         |                 |     |     |     |      |  |  |  |
|------------------|-------------------------|-----------------|-----|-----|-----|------|--|--|--|
|                  | PARAMETER               | TEST CONDITIONS | MIN | TYP | MAX | UNIT |  |  |  |
| I <sub>I/O</sub> | Input/outputcapacitance | $V_{Out} = 0 V$ |     |     | 7   | pF   |  |  |  |
| Cl               | Input capacitance       | V = 0 V         |     |     | 5   | þг   |  |  |  |



## AC TEST CONDITIONS, INPUT PULSE LEVELS VI = 0 V to 3.0 V, $t_R$ = $t_F$ = 5 NS, VREF = 1.5 V

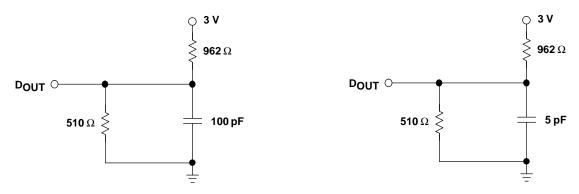


Figure 1. Output Load A

Figure 2. Output Load B

## **OPERATING CHARACTERISTICS**

## READ CYCLE (T<sub>A</sub> = T<sub>OPR</sub>, V<sub>CC</sub> = 5 V)

|                  | PARAMETER                          | TEST CONDITIONS | MIN | MAX | UNIT |
|------------------|------------------------------------|-----------------|-----|-----|------|
| tRC              | Read cycle time                    |                 | 200 |     | ns   |
| t <sub>A</sub> A | Address access time                | Output load A   |     | 100 | ns   |
| tACS             | Chip select access time            | Output load A   |     | 100 | ns   |
| tOE              | Output enable to output valid      | Output load A   |     | 100 | ns   |
| tCLZ             | Chip select to output low Z        | Output load B   | 8   |     | ns   |
| tOLZ             | Output enable until output low Z   | Output load B   | 0   |     | ns   |
| tCHZ             | Output enable until output high Z  | Output load B   | 0   | 45  | ns   |
| tOHZ             | Output disable until output high Z | Output load B   | 0   | 45  | ns   |
| tOH              | Output hold from address change    | Output load A   | 10  |     | ns   |

## READ CYCLE (T<sub>A</sub> = T<sub>OPR</sub>, V<sub>CC</sub> = 3.3 V)

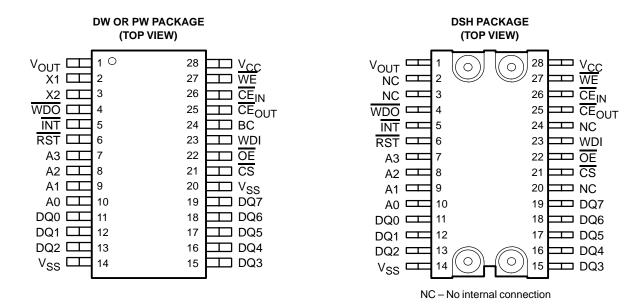
|                  |                                    | ·               |     |     |      |
|------------------|------------------------------------|-----------------|-----|-----|------|
|                  | PARAMETER                          | TEST CONDITIONS | MIN | MAX | UNIT |
| tRC              | Read cycle time                    |                 | 300 |     | ns   |
| t <sub>AA</sub>  | Address access time                | Output load A   |     | 150 | ns   |
| tACS             | Chip select access time            | Output load A   |     | 150 | ns   |
| <sup>t</sup> OE  | Output enable to output valid      | Output load A   |     | 150 | ns   |
| <sup>t</sup> CLZ | Chip select to output low Z        | Output load B   | 15  |     | ns   |
| tOHL             | Output enable until output low Z   | Output load B   | 0   |     | ns   |
| <sup>t</sup> CLH | Output enable until output high Z  | Output load B   | 0   | 60  | ns   |
| tOLZ             | Output disable until output high Z | Output load B   | 0   | 60  | ns   |
| tOH              | Output hold from address change    | Output load A   | 18  |     | ns   |

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bq4802Y



#### **PIN ASSIGNMENTS**



#### **Terminal Functions**

| TERMI           | INAL  |     | DECORPORTION                                                                                                                                                                                                                                                                                        |
|-----------------|-------|-----|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME            | NO.   | 1/0 | DESCRIPTION                                                                                                                                                                                                                                                                                         |
| A0              | 10    |     | A0 – A3 allow access to the 16 bytes of real-time clock and control registers.                                                                                                                                                                                                                      |
| A1              | 9     |     |                                                                                                                                                                                                                                                                                                     |
| A2              | 8     |     |                                                                                                                                                                                                                                                                                                     |
| А3              | 7     |     |                                                                                                                                                                                                                                                                                                     |
| ВС              | 24(1) |     | BC should be connected to a 3-V backup cell. A voltage within the V <sub>BC</sub> range on the BC pin should be present upon power up to provide proper oscillator start-up. Not accessible in module packages.                                                                                     |
| CEIN            | 26    |     | Input to the chip-enable gating circuit                                                                                                                                                                                                                                                             |
| CEOUT           | 25    |     | CE <sub>OUT</sub> goes low only when CE <sub>IN</sub> is low and V <sub>CC</sub> is above the power fail threshold. If CE <sub>IN</sub> is low, and power fail occurs, CE <sub>OUT</sub> stays low for 100 µs or until CE <sub>IN</sub> goes high, whichever occurs first.                          |
| CS              | 21    | - 1 | Chip-selectinput                                                                                                                                                                                                                                                                                    |
| DQ0             | 11    | I   | DQ0-DQ7 provide x8 data for real-time clock information. These pins connect to the memory data bus.                                                                                                                                                                                                 |
| DQ1             | 12    | I   |                                                                                                                                                                                                                                                                                                     |
| DQ2             | 13    | - 1 |                                                                                                                                                                                                                                                                                                     |
| DQ3             | 15    | - 1 |                                                                                                                                                                                                                                                                                                     |
| DQ4             | 16    | 1   |                                                                                                                                                                                                                                                                                                     |
| DQ5             | 17    | I   |                                                                                                                                                                                                                                                                                                     |
| DQ6             | 18    | I   |                                                                                                                                                                                                                                                                                                     |
| DQ7             | 19    | 1   |                                                                                                                                                                                                                                                                                                     |
| ĪNT             | 5     |     | INT goes low when a power fail, periodic, or alarm condition occurs. INT is an open-drain output.                                                                                                                                                                                                   |
| OE              | 22    |     | OE provides the read control for the RTC memory locations.                                                                                                                                                                                                                                          |
| RST             | 6     |     | $\overline{RST}$ goes low whenever V_CC falls below the power fail threshold. $\overline{RST}$ remains low for 200 ms (typical) after V_CC crosses the threshold on power-up. The bq4802Y/bq4802LY also enters the reset cycle when RST is released from being pulled low for more than 1 $\mu s$ . |
| VCC             | 28    | ı   | 5-V or 3.3-V input                                                                                                                                                                                                                                                                                  |
| VOUT            | 1     | 0   | $V_{OUT}$ provides the higher of $V_{CC}$ or $V_{BC}$ , switched internally, to supply external RAM.                                                                                                                                                                                                |
|                 | 14    |     | Ground                                                                                                                                                                                                                                                                                              |
| V <sub>SS</sub> | 20(1) |     |                                                                                                                                                                                                                                                                                                     |

<sup>(1)</sup> This pin should be left unconnected (NC) when using the SNAPHAT (DSH) package.



## **Terminal Functions (Continued)**

| TERM | INAL |     | DESCRIPTION                                                                                                                                                                                                                                                                                                                                                              |
|------|------|-----|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME | NO.  | 1/0 | DESCRIPTION                                                                                                                                                                                                                                                                                                                                                              |
| WDI  | 23   | I   | WDI is a three-level input. If WDI remains either high or low for longer than the watchdog time-out period (1.5-s default), WDO goes low. WDO remains low until the next transition at WDI. Leaving WDI unconnected disables the watchdog function. WDI connects to an internal voltage divider between VOUT and Vss, which sets it to mid-supply when left unconnected. |
| WDO  | 4    |     | WDO goes low if WDI remains either high or low longer than the watchdog time-out period. WDO returns high on the next transition at WDI. WDO remains high if WDI is unconnected.                                                                                                                                                                                         |
| WE   | 27   |     | WE provides the write control for the RTC memory locations.                                                                                                                                                                                                                                                                                                              |
| X1   | 2(1) |     | Crystal connection                                                                                                                                                                                                                                                                                                                                                       |
| X2   | 3(1) |     |                                                                                                                                                                                                                                                                                                                                                                          |

#### **FUNCTIONAL BLOCK DIAGRAM**

Figure 3 is a block diagram of the bq4802Y/bq4802LY. The following sections describe the bq4802Y/bq4802LY functional operation including clock interface, data-retention modes, power-on reset timing, watchdog timer activation, and interrupt generation.

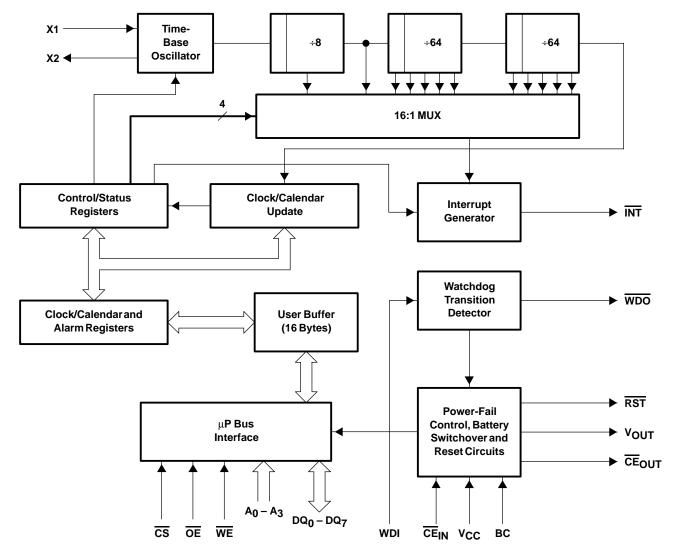
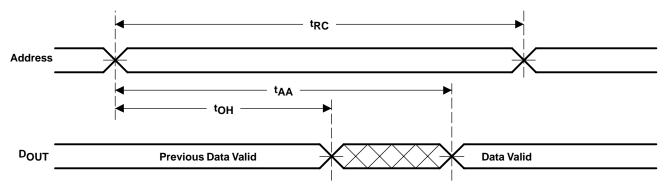


Figure 3. Block Diagram



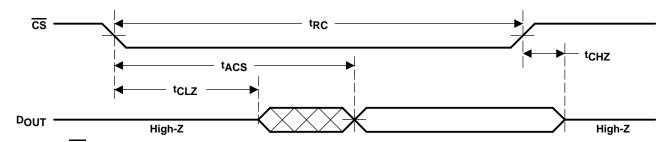
#### **READ CYCLE TIMING DIAGRAMS**



NOTES: A. WE is held high for a read cycle.

B. Device is continuously selected:  $\overline{CS} = \overline{OE} = V_{II}$ .

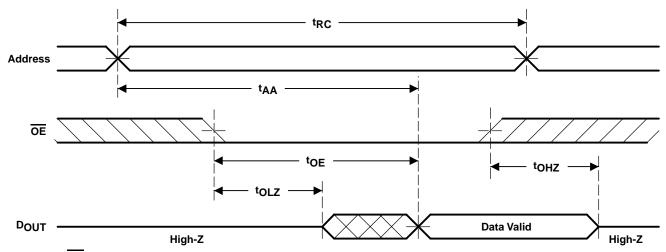
Figure 4. Read Cycle No. 1 - Address Access



NOTES: A. WE is held high for a read cycle.

- B. Device is continuously selected:  $\overline{CS} = \overline{OE} = V_{IL}$ .
- C.  $\overline{OE} = V_{IL}$ .

Figure 5. Read Cycle No. 2 - CS Access

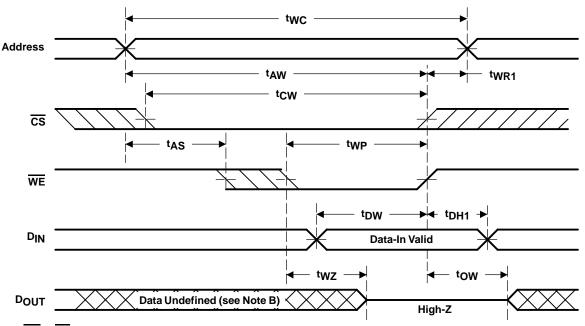


NOTES: A.  $\overline{\text{WE}}$  is held high for a read cycle. B.  $\overline{\text{CS}} = \text{V}_{\text{IL}}$ .

Figure 6. Read Cycle No. 3 - OE Access



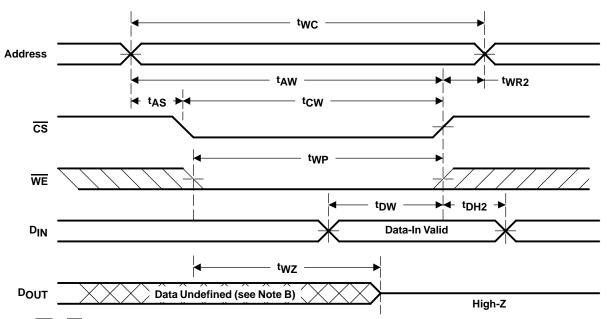
#### WRITE CYCLE TIMING DIAGRAMS



NOTES: A.  $\overline{\text{WE}}$  or  $\overline{\text{CS}}$  must be held high <u>dur</u>ing address transition.

- B. Because I/O may be active (OE low) during the period, data input signals of opposite polarity to the outputs must be applied.
- C. If  $\overline{OE}$  is high, the I/O pins remain in a state of high impedance.

Figure 7. Write Cycle No. 1 – WE Controlled



NOTES: A.  $\overline{\text{WE}}$  or  $\overline{\text{CS}}$  must be held high <u>during</u> address transition.

- B. Because I/O may be active (OE low) during the period, data input signals of opposite polarity to the outputs must be applied.
- C. If  $\overline{\mathsf{OE}}$  is high, the I/O pins remain in a state of high impedance.
- D. Either twR1 or twR2 must be met.
- E. Either t<sub>DH1</sub> or t<sub>DH2</sub> must be met.

Figure 8. Write Cycle No. 2 - CS Controlled



## WRITE CYCLE (T<sub>A</sub> = T<sub>OPR</sub>, V<sub>CC</sub> = 5 V)

|                 | PARAMETER                           | TEST CONDITIONS                                                  | MIN | MAX | UNIT |
|-----------------|-------------------------------------|------------------------------------------------------------------|-----|-----|------|
| tWC             | Write cycle time                    |                                                                  | 200 |     | ns   |
| tcw             | Chip select to end of write         | See Note 1                                                       | 195 |     | ns   |
| t <sub>AW</sub> | Address valid to end of write       | See Note 1                                                       | 195 |     | ns   |
| tAS             | Address setup time                  | Measured from address valid to beginning of write <sup>(2)</sup> | 30  |     | ns   |
| t <sub>WP</sub> | Write pulse width                   | Measured from beginning of write to end of write(1)              | 165 |     | ns   |
| tWR1            | Write recovery time (write cycle 1) | Measured from WE going high to end of write cycle(3)             | 5   |     | ns   |
| tWR2            | Write recovery time (write cycle 2) | Measured from CS going high to end of write cycle(3)             | 15  |     | ns   |
| tDW             | Data valid to end of write          | Measured to first low-to-high transition of either CS or WE      | 50  |     | ns   |
| tDH1            | Data hold time (write cycle 1)      | Measured from WE going high to end of write cycle(4)             | 0   |     | ns   |
| tDH2            | Data hold time (write cycle 2)      | Measured from CS going high to end of write cycle(4)             | 10  |     | ns   |
| twz             | Write enable to output high Z       | I/O pins are in output state.(5)                                 | 0   | 45  | ns   |
| tow             | Output active from end of write     | I/O pins are in output state.(5)                                 | 0   |     | ns   |

- (1) A write cycle ends at the earlier transition of  $\overline{CS}$  going high and  $\overline{WE}$  going high.
  (2) A write occurs during the overlap of a low  $\overline{CS}$  and a low  $\overline{WE}$ . A write cycle begins at the later transition of  $\overline{CS}$  going low or  $\overline{WE}$  going low.
  (3) Either tWR1 or tWR2 must be met.
  (4) Either tDH1 or tDH2 must be met.
  (5) If  $\overline{CS}$  goes low simultaneously with  $\overline{WE}$  going low or after  $\overline{WE}$  going low, the outputs remain in high Z state.

## WRITE CYCLE (T<sub>A</sub> = T<sub>OPR</sub>, V<sub>CC</sub> = 3.3 V)

|                  | PARAMETER                           | TEST CONDITIONS                                             | MIN | MAX | UNIT |
|------------------|-------------------------------------|-------------------------------------------------------------|-----|-----|------|
| tWC              | Write cycle time                    |                                                             | 300 |     | ns   |
| tCW              | Chip select to end of write         | See Note 1                                                  | 250 |     | ns   |
| t <sub>AW</sub>  | Address valid to end of write       | See Note 1                                                  | 250 |     | ns   |
| t <sub>AS</sub>  | Address setup time                  | Measured from address valid to beginning of write(2)        | 56  |     | ns   |
| twp              | Write pulse width                   | Measured from beginning of write to end of write(1)         | 280 |     | ns   |
| tWR1             | Write recovery time (write cycle 1) | Measured from WE going high to end of write cycle(3)        | 8   |     | ns   |
| tWR2             | Write recovery time (write cycle 2) | Measured from CS going high to end of write cycle(3)        | 25  |     | ns   |
| tDW              | Data valid to end of write          | Measured to first low-to-high transition of either CS or WE | 80  |     | ns   |
| tDH1             | Data hold time (write cycle 1)      | Measured from WE going high to end of write cycle(4)        | 0   |     | ns   |
| t <sub>DH2</sub> | Data hold time (write cycle 2)      | Measured from CS going high to end of write cycle(4)        | 15  |     | ns   |
| tWZ              | Write enable to output high Z       | I/O pins are in output state.(5)                            | 0   | 60  | ns   |
| tow              | Output active from end of write     | I/O pins are in output state.(5)                            | 0   |     | ns   |

- (1) A write cycle ends at the earlier transition of  $\overline{CS}$  going high and  $\overline{WE}$  going high.
- (2) A write occurs during the overlap of a low  $\overline{\text{CS}}$  and a low  $\overline{\text{WE}}$ . A write cycle begins at the later transition of  $\overline{\text{CS}}$  going low or  $\overline{\text{WE}}$  going low.
- (3) Either tWR1 or tWR2 must be met.
- (4) Either t<sub>DH1</sub> or t<sub>DH2</sub> must be met.
- (5) If  $\overline{\text{CS}}$  goes low simultaneously with  $\overline{\text{WE}}$  going low or after  $\overline{\text{WE}}$  going low, the outputs remain in high Z state.

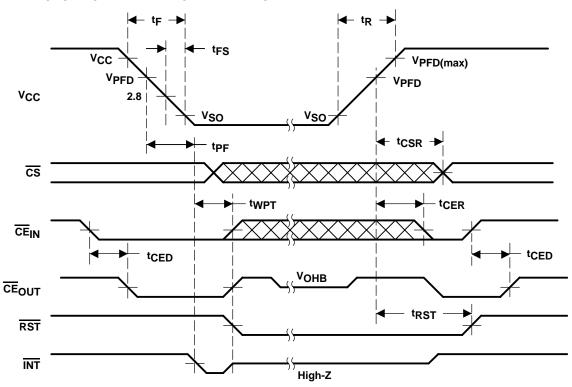


## POWER-DOWN/POWER-UP TIMING $(T_A = T_{OPR})$

|                | PARAMETER                                                     |          | TEST CONDITIONS  | MIN  | TYP | MAX  | UNIT |  |
|----------------|---------------------------------------------------------------|----------|------------------|------|-----|------|------|--|
| tF             | V <sub>CC</sub> slew rate fall time                           |          | 3.0 V to 0 V     | 300  |     |      |      |  |
| t <sub>R</sub> | V <sub>CC</sub> slew rate rise time                           |          | Vso to VPDF(max) | 100  |     |      |      |  |
|                |                                                               | bq4802Y  |                  | 6    |     | 24   |      |  |
| tPF            | Interrupt delay time from V <sub>PFD</sub>                    | bq4802LY |                  | 10   |     | 40   | μs   |  |
|                |                                                               | bq4802Y  | See Note 1       | 90   | 100 | 125  |      |  |
| tWPT           | Write-protect time for external SRAM                          | bq4802LY | See Note 1       | 150  | 170 | 210  |      |  |
|                | <del></del>                                                   | bq4802Y  | See Note 2       | 100  | 200 | 300  |      |  |
| tCSR           | CS at V <sub>HI</sub> after power-up                          | bq4802LY | See Note 2       | 170  | 330 | 500  |      |  |
| tRST           | V <sub>PFD</sub> to RST active (reset active time-out period) |          |                  | tCSR |     | tCSR | ms   |  |
| tCER           | Device enable recovery time                                   |          | See Note 3       | tCSR |     | tCSR |      |  |
|                |                                                               | bq4802Y  |                  |      | 9   | 15   | ns   |  |
| tCED           | Device enable propagation delay time to external SRAM         | bq4802LY | Output load A    |      | 15  | 25   |      |  |
| tPBL           | Push-button low time                                          |          | 1                |      |     | μs   |      |  |

<sup>(1)</sup> Delay after V<sub>CC</sub> slews down past V<sub>PFD</sub> before SRAM is write protected and RST activated.

## CAUTION:NEGATIVE UNDERSHOOTS BELOW THE ABSOLUTE MAXIMUM RATING OF -0.3 V IN BATTERY-BACKUP MODE MAY AFFECT DATA INTEGRITY.



NOTES: A. <u>PWRIE set to</u> 1 to enable power fail interrupt.

B. RST and INT are open drain and require and external pullup resistor.

Figure 9. Power-Down/Power-Up Timing Diagram

<sup>(2)</sup> Internal write-protection period after V<sub>CC</sub> passes V<sub>PFD</sub> on power up.

<sup>(3)</sup> Time during which external SRAM is write protected after VCC passes VPFD on power up.





Figure 10. Push-Button Reset Timing



#### **FUNCTIONAL DESCRIPTION**

The following sections describe the bq4802Y/bq4802LY functional operation including clock interface, data-retention modes, power-on reset timing, watchdog timer activation, and interrupt generation.

**Table 1. Operational Truth Table** 

| VCC                      | CS              | OE  | WE  | CEOUT | V <sub>OUT</sub>  | MODE     | DQ              | POWER               |
|--------------------------|-----------------|-----|-----|-------|-------------------|----------|-----------------|---------------------|
| < VCC(MAX)               | $V_{IH}$        | Х   | Х   | CEIN  | V <sub>OUT1</sub> | Deselect | High Z          | Standby             |
|                          | V <sub>IL</sub> | Х   | VIL | CEIN  | VOUT1             | Write    | D <sub>IN</sub> | Active              |
| > VCC(MIN)               | $V_{IL}$        | VIL | VIH | CEIN  | VOUT1             | Read     | DOUT            | Active              |
|                          | $V_{IL}$        | VIH | VIH | CEIN  | VOUT1             | Read     | High-Z          | Active              |
| <vpfd(min>VSO</vpfd(min> | Х               | Х   | Х   | Vон   | VOUT1             | Deselect | High-Z          | CMOS standby        |
| ≤V <sub>SO</sub>         | Х               | Х   | Х   | Vонв  | V <sub>OUT2</sub> | Deselect | High-Z          | Battery-backup mode |

#### **ADDRESS MAP**

The bq4802Y/bq4802LY provides 16 bytes of clock and control status registers. Table 1 is a map of the bq4802Y/bq4802LY registers, and Table 2 describes the register bits.

Table 2. Clock and Control Register Map

| Addr<br>(h) | D7     | D6      | D5            | D4        | D3  | D2                 | D1            | D0                 | Range (h)        | Register      |
|-------------|--------|---------|---------------|-----------|-----|--------------------|---------------|--------------------|------------------|---------------|
| 0           | 0      | 1       | 0-second dig  | it        |     | 1-seco             | nd digit      | 00–59              | Seconds          |               |
| 1           | ALM1   | ALM0    |               |           |     | 1 0000             | n al aliait   |                    | 00–59            | Seconds alarm |
| ı           | ALIVIT | 1       | 0-second dig  | it        |     | 1-8000             | nd digit      | 00-59              | Seconds alaim    |               |
| 2           | 0      | 1       | 10-minutedigi | t         |     | 1-minu             | ıte digit     |                    | 00–59            | Minutes       |
| 3           | ALM1   | ALM0    |               |           |     | 1 minu             | ıto digit     |                    | 00–59            | Minutesalarm  |
| 3           | ALIVIT | 1       | 10-minutedigi | t         |     | 1-1111110          | ıte digit     | 00-59              | WilliuleSalaiiii |               |
| 4           | PM/AM  | 0       | 10-hou        | urdigit   |     | 1-hou              | ır digit      | 01–12AM<br>81–92PM | Hours            |               |
| 5           | ALM1   | ALMO    | 10 ho         | ur aliait |     | 1 hou              | di ait        | 01-12AM            | Hours alarm      |               |
| 5           | PM/AM  | ALM0    | 10-1100       | urdigit   |     | 1-1100             | ırdigit       | 81-92PM            | nours alaim      |               |
| 6           | 0      | 0       | 10-da         | y digit   |     | 1-day              | y digit       | 01–31              | Day              |               |
| 7           | ALM1   | ALM0    | 10-da         | y digit   |     | 1-day              | y digit       | 01–31              | Day alarm        |               |
| 8           | 0      | 0       | 0             | 0         | 0   | da                 | ay of week di | git                | 01–07            | Day of Week   |
| 9           | 0      | 0       | 0             | 10 mo.    |     | 1-mon              | ıth digit     |                    | 01–12            | Month         |
| Α           |        | 10-ye   | ar digit      |           |     | 1-yea              | ır digit      |                    | 00–99            | Year          |
| В           | (1)    | WD2     | WD1           | WD0       | RS3 | RS2                | RS1           | RS0                | -                | Rates         |
| С           | (1)    | (1)     | (1)           | (1)       | AIE | PIE                | PWRIE         | ABE                | -                | Enables       |
| D           | (1)    | (1)     | (1)           | (1)       | AF  | PF                 | PWRF          | BVF                | -                | Flags         |
| Е           | (1)    | (1)     | (1)           | (1)       | UTI | UTI STOP 24/12 DSE |               |                    |                  | Control       |
| F           |        | 10-cent | ury digit     |           |     | 1-centu            | 00–99         | Century            |                  |               |

<sup>(1)</sup> Unused bits; cannot be written to and read as 0.

<sup>(2)</sup> Internal write-protection period after VCC passes VPFD on power up.

<sup>(3)</sup> Clock calendar data in BCD. Automatic leap year adjustment up to year 2100.

<sup>(4)</sup> PM/AM = 1 for PM and 0 for AM.

<sup>(5)</sup> DSE = 1 to enable daylight savings adjustment.

<sup>(6)</sup> 24/12 = 1 to enable 24—hour data representation and 0 for 12—hour data representation.

<sup>(7)</sup> Day of week coded as Sunday = 1 through Saturday = 7

<sup>(8)</sup> BVF = 1 for valid BC input (9) STOP = 1 to turn the RTC on and 0 stops the RTC in battery-backup mode



Table 3. Clock and Control Register Map

| BIT       | DESCRIPTION                                   |
|-----------|-----------------------------------------------|
| 24/12     | 24- or 12-hour data representation            |
| ABE       | Alarm interrupt enable in battery-backup mode |
| AF        | Alarm interrupt flag                          |
| AIE       | Alarm interrupt enable                        |
| ALM0-ALM1 | Alarm mask bits                               |
| BVF       | Battery-validflag                             |
| DSE       | Daylight savings enable                       |
| PF        | Periodic interrupt flag                       |
| PIE       | Periodic interrupt enable                     |
| PM/AM     | PM or AM indication                           |
| PWRF      | Power-fail interrupt flag                     |
| PWRIE     | Power-fail interrupt enable                   |
| RS0-RS3   | Periodic interrupt rate                       |
| STOP      | Oscillator stop and start                     |
| UTI       | Update transfer inhibit                       |
| WD0-WD2   | Watchdog time-out rate                        |

#### **CLOCK MEMORY INTERFACE**

The bq4802Y/bq4802LY has the same interface for clock/calendar and control information as standard SRAM. To read and write to these locations, the user must put the bq4802Y/bq4802LY in the proper mode and meet the timing requirements.

#### **READ MODE**

The bq4802Y/bq4802LY is in read mode whenever  $\overline{\text{OE}}$  (output enable) is low and  $\overline{\text{CS}}$  (chip select) is low. The unique address, specified by the four address inputs, defines which one of the 16 clock/calendar bytes is to be accessed. The bq4802Y/bq4802LY makes valid data available at the data I/O pins within  $t_{AA}$  (address access time). This occurs after the last address input signal is stable, and providing the  $\overline{\text{CS}}$  and  $\overline{\text{OE}}$  (output enable) access times are met. If the  $\overline{\text{CS}}$  and  $\overline{\text{OE}}$  access times are not met, valid data is available after the latter of chip select access time ( $t_{ACS}$ ) or output enable access time ( $t_{OE}$ ).

 $\overline{\text{CS}}$  and  $\overline{\text{OE}}$  control the state of the eight three-state data I/O signals. If the outputs are activated before  $t_{AA}$ , the data lines are driven to an indeterminate state until  $t_{AA}$ . If the address inputs are changed while  $\overline{\text{CS}}$  and  $\overline{\text{OE}}$  remain low, output data remains valid for  $t_{OH}$  (output data hold time), but goes indeterminate until the next address access.

#### **WRITE MODE**

The bq4802Y/bq4802LY is in write mode whenever  $\overline{WE}$  and  $\overline{CS}$  are active. The start of a write is referenced from the latter-occurring falling edge of  $\overline{WE}$  or  $\overline{CS}$ . A write is terminated by the earlier rising edge of  $\overline{WE}$  or  $\overline{CS}$ . The addresses must be held valid throughout the cycle.  $\overline{CS}$  or

 $\overline{\text{WE}}$  must return high for a minimum of  $t_{WR2}$  from  $\overline{\text{CS}}$  or  $t_{WR1}$  from  $\overline{\text{WE}}$  prior to the initiation of another read or write cycle.

Data-in must be valid  $t_{DW}$  prior to the end of write and remain valid for  $t_{DH1}$  or  $t_{DH2}$  afterward.  $\overline{OE}$  should be kept high during write cycles to avoid bus contention; although, if the output bus has been activated by a low on  $\overline{CS}$  and  $\overline{OE}$ , a low on  $\overline{WE}$  disables the outputs  $t_{WZ}$  after  $\overline{WE}$  falls.

#### READING THE CLOCK

Once every second, the user-accessible clock/calendar locations are updated simultaneously from the internal real-time counters. To prevent reading data in transition, updates to the bq4802Y/bq4802LY clock registers should be halted. Updating is halted by setting the update transfer inhibit (UTI) bit D3 of the control register E. As long as the UTI bit is 1, updates to user-accessible clock locations are inhibited. Once the frozen clock information is retrieved by reading the appropriate clock memory locations, the UTI bit should be reset to 0 in order to allow updates to occur from the internal counters. Because the internal counters are not halted by setting the UTI bit, reading the clock locations has no effect on clock accuracy. Once the UTI bit is reset to 0, the internal registers update within one second the user-accessible registers with the correct time. A halt command issued during a clock update allows the update to occur before freezing the data.

#### SETTING THE CLOCK

The UTI bit must also be used to set the bq4802Y/bq4802LY clock. Once set, the locations can be written with the desired information in BCD format. Resetting the UTI bit to 0 causes the written values to be transferred to the internal clock counters and allows updates to the user-accessible registers to resume within one second.

## STOPPING AND STARTING THE CLOCK OSCILLATOR

The bq4802Y/bq4802LY clock can be programmed to turn off when the part goes into battery back-up mode by setting  $\overline{\text{STOP}}$  to 0 prior to power down. If the board using the bq4802Y/bq4802LY is to spend a significant period of time in storage, the  $\overline{\text{STOP}}$  bit can be used to preserve some battery capacity.  $\overline{\text{STOP}}$  set to 1 keeps the clock running when V<sub>CC</sub> drops below V<sub>SO</sub>. With V<sub>CC</sub> greater than V<sub>SO</sub>, the bq4802Y/bq4802LY clock runs regardless of the state of  $\overline{\text{STOP}}$ .

#### POWER-DOWN/POWER-UP CYCLE

The bq4802Y/bq4802LY continuously monitors  $V_{CC}$  for out-of-tolerance. During a power failure, when  $V_{CC}$  falls below  $V_{PFD}$ , the bq4802Y/bq4802LY write-protects the clock and storage registers. The power source is switched to BC when  $V_{CC}$  is less than  $V_{PFD}$  and BC is greater than  $V_{PFD}$ , or when  $V_{CC}$  is less than  $V_{BC}$  and  $V_{BC}$  is less than



 $V_{PFD}$ . RTC operation and storage data are sustained by a valid backup energy source. When  $V_{CC}$  is above  $V_{PFD}$ , the power source is  $V_{CC}$ . Write-protection continues for  $t_{CSR}$  time after  $V_{CC}$  rises above  $V_{PFD}$ .

An external CMOS static RAM is battery-backed using the  $V_{OUT}$  and chip enable output pins from the bq4802Y/bq4802LY. As the voltage input  $V_{CC}$  slews down during a power failure, the chip enable output,  $\overline{CE}_{OUT}$ , is forced inactive independent of the chip enable input  $\overline{CE}_{IN}$ .

This activity unconditionally write-protects the external SRAM as  $V_{CC}$  falls below  $V_{PFD}$ . If a memory access is in progress to the external SRAM during power-fail detection, that memory cycle continues to completion before the memory is write-protected. If the memory cycle is not terminated within time  $t_{WPT}$ , the chip enable output is unconditionally driven high, write-protecting the controlled SRAM.

As the supply continues to fall past  $V_{PFD}$ , an internal switching device forces  $V_{OUT}$  to the external backup energy source.  $\overline{CE}_{OUT}$  is held high by the  $V_{OUT}$  energy source.

During power up,  $V_{OUT}$  is switched back to the main supply as  $V_{CC}$  rises above the backup cell input voltage sourcing  $V_{OUT}$ . If  $V_{PFD} < V_{BC}$  on the bq4802Y/bq4802LY the switch to the main supply occurs at  $V_{PFD}$ . CEOUT is held inactive for time  $t_{CER}$  (200-ms maximum) after the power supply has reached  $V_{PFD}$ , independent of the  $\overline{CE}_{IN}$  input, to allow for processor stabilization.

During power-valid operation, the  $\overline{CE}_{IN}$  input is passed through to the  $\overline{CE}_{OUT}$  output with a propagation delay of less than 12 ns. Figure 2 shows the hardware hookup for the external RAM, battery, and crystal.

A primary backup energy source input is provided on the bq4802Y/bq4802LY. The BC input accepts a 3-V primary battery, typically some type of lithium chemistry. Since the bq4802Y/bq4802LY provides for reverse battery charging protection, no diode or current limiting resistor is needed in series with the cell. To prevent battery drain when there is no valid data to retain, V<sub>OUT</sub> and CE<sub>OUT</sub> are internally isolated from BC by the initial connection of a battery. Following the first application of V<sub>CC</sub> above V<sub>PFD</sub>, this isolation is broken, and the backup cell provides power to  $V_{OUT}$  and  $\overline{CE}_{OUT}$  for the external SRAM. The crystal should be located as close to X1 and X2 as possible and meet the specifications in the crystal specifications section of the electrical characteristics tables. With the specified crystal, the bg4802Y/bg4802LY RTC is accurate to within one minute per month at room temperature. In the absence of a crystal, a 32.768-kHz waveform can be fed into X1 with X2 grounded. The power source and crystal are integrated into the SNAPHAT modules.

#### Power-On Reset

The bq4802Y/bq4802LY provides a power-on reset, which pulls the RST pin low on power down and remains low on power up for  $t_{RST}$  after  $V_{CC}$  passes  $V_{PFD}$ . With valid battery voltage on BC, RST remains valid for  $V_{CC} = V_{SS}$ .

#### Push-Button Reset

The bq4802Y/bq4802LY also provides a push-button override to the reset when the device is not already in a reset cycle. When the RST pin is released after being pulled low for 1  $\mu$ s then the RST stays low for 200 ms (typical).

#### WATCHDOG TIMER

The watchdog monitors microprocessor activity through the watchdog input (WDI). To use the watchdog function, connect WDI to a bus line or a microprocessor I/O line. If WDI remains high or low for longer than the watchdog time-out period (1.5 seconds default), the bq4802Y/bq4802LY asserts WDO and RST.

#### Watchdog Input

The bq4802Y/bq4802LY resets the watchdog timer if a change of state (high-to-low, low-to-high, or a minimum 100 ns pulse) occurs at the watchdog input (WDI) during the watchdog period. The watchdog time-out is set by WD0 – WD2 in register B. The bq4802Y/bq4802LY maintains the watchdog time-out programming through power cycles. The default state (no valid battery power) of WD0 – WD2 is 000 or 1.5 s on power up. Table 3 shows the programmable watchdog time-out rates. The watchdog time-out period immediately after a reset is equal to the programmed watchdog time-out.

To disable the watchdog function, leave WDI floating. An internal resistor network (100-k $\Omega$  equivalent impedance at WDI) biases WDI to approximately 1.6 V. Internal comparators detect this level and disable the watchdog timer. When V<sub>CC</sub> is below the power-fail threshold, the bq4802Y/bq4802LY disables the watchdog function and disconnects WDI from its internal resistor network, thus making it high impedance.

#### **Watchdog Output**

The watchdog output ( $\overline{WDO}$ ) remains high if there is a transition or pulse at WDI during the watchdog timeout period. The bq4802Y/bq4802LY disables the watchdog function and  $\overline{WDO}$  is a logic high when V<sub>CC</sub> is below the power fail threshold, battery-backup mode is enabled, or WDI is an open circuit. In watchdog mode, if no transition occurs at WDI during the watchdog time-out period, the bq4802Y/bq4802LY asserts  $\overline{RST}$  for the reset time-out period t1. WDO goes low and remains low until the next transition at WDI. If WDI is held high or low indefinitely,  $\overline{RST}$  generates pulses (t1 seconds wide) every t3 seconds. Figure 11 shows the watchdog timing.



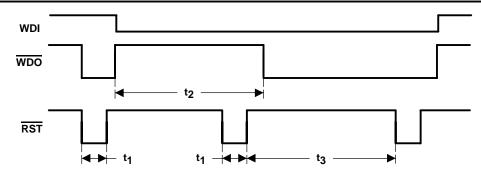


Figure 11. Watchdog Time-Out Period and Reset Active Time

Table 4. Watchdog and Reset Timeout Rates

| WD2 | WD1 | WD0 | WATCHDOG<br>TIMEOUT PERIOD | RESET TIMEOUT PERIOD |
|-----|-----|-----|----------------------------|----------------------|
| 0   | 0   | 0   | 1.50 s                     | 0.25 ms              |
| 0   | 0   | 1   | 23.4375 ms                 | 3.9063 ms            |
| 0   | 1   | 0   | 46.875 ms                  | 7.8125 ms            |
| 0   | 1   | 1   | 93.750 ms                  | 15.625 ms            |
| 1   | 0   | 0   | 187.5 ms                   | 31.25 ms             |
| 1   | 0   | 1   | 375 ms                     | 62.5 ms              |
| 1   | 1   | 0   | 750 ms                     | 125 ms               |
| 1   | 1   | 1   | 3.0 s                      | 0.5 s                |

**INTERRUPTS** 

The bq4802Y/bq4802LY allows three individually selected interrupt events to generate an interrupt request on the INT pin. These three interrupt events are:

- The periodic interrupt, programmable to occur once every 30.5 μs to 500 ms.
- The alarm interrupt, programmable to occur once per second to once per month.
- The power-fail interrupt, which can be enabled to be asserted when the bq4802Y/bq4802LY detects a power failure.

An individual interrupt-enable bit in register C, the interrupts register, enables the periodic, alarm and power-fail interrupts. When an event occurs, its event flag bit in the flags register, register D, is set. If the corresponding event enable bit is also set, then an interrupt request is generated. Reading the flags register clears all flag bits and makes INT high impedance. To reset the flag register, the bq4802Y/bq4802LY addresses must be held stable at register D for at least 50 ns to avoid inadvertent resets.

#### Periodic Interrupt

Bits RS3 – RS0 in the interrupt register program the rate for the periodic interrupt. The user can interpret the interrupt in two ways, either by polling the flags register for PF assertion or by setting PIE so that  $\overline{\text{INT}}$  goes active when the bq4802Y/bq4802LY sets the periodic flag. Reading the flags register resets the PF bit and returns  $\overline{\text{INT}}$  to the high-impedance state. Table 5 shows the periodic rates.

**Table 5. Periodic Interrupt Rates** 

|     | REGIST | ER BITS |     | PERIODIC<br>INTERRUPT |
|-----|--------|---------|-----|-----------------------|
| RS3 | RS2    | RS1     | RS0 | PERIOD                |
| 0   | 0      | 0       | 0   | NONE                  |
| 0   | 0      | 0       | 1   | 30.5175 μs            |
| 0   | 0      | 1       | 0   | 61.035 μs             |
| 0   | 0      | 1       | 1   | 122.070 μs            |
| 0   | 1      | 0       | 0   | 244.141 μs            |
| 0   | 1      | 0       | 1   | 488.281 μs            |
| 0   | 1      | 1       | 0   | 976.5625 μs           |
| 0   | 1      | 1       | 1   | 1.95315 ms            |
| 1   | 0      | 0       | 0   | 3.90625 ms            |
| 1   | 0      | 0       | 1   | 7.8125 ms             |
| 1   | 0      | 1       | 0   | 15.625 ms             |
| 1   | 0      | 1       | 1   | 31.25 ms              |
| 1   | 1      | 0       | 0   | 62.5 ms               |
| 1   | 1      | 0       | 1   | 125 ms                |
| 1   | 1      | 1       | 0   | 250 ms                |
| 1   | 1      | 1       | 1   | 500 ms                |

#### **ALARM INTERRUPT**

Registers 1, 3, 5, and 7 program the real-time clock alarm. During each update cycle, the bg4802Y/bg4802LY compares the date, hours, minutes, and seconds in the clock registers with the corresponding alarm registers. If a match between all the corresponding bytes is found, the alarm flag AF in the flags register is set. If the alarm interrupt is enabled with AIE, an interrupt request is generated on INT. The alarm condition is cleared by a read to the flags register. ALM1 - ALM0 in the alarm registers, mask each alarm compare byte. Setting ALM1 (D7) and ALM0 (D6) to 1 masks an alarm byte. Alarm byte masking can be used to select the frequency of the alarm interrupt, according to Table 6. The alarm interrupt can be made active while the bq4802Y/bq4802LY is in the batterybackup mode by setting ABE in the interrupts register. Normally, the INT pin goes high-impedance during battery backup. With ABE set, INT is driven low if an alarm condition occurs and the AIE bit is set.



## Table 6. Alarm Frequency

| 1h        | 3h        | 5h        | 7h        | ALADM EDECLIENCY                                    |
|-----------|-----------|-----------|-----------|-----------------------------------------------------|
| ALM1-ALM0 | ALM1-ALM0 | ALM1-ALM0 | ALM1-ALM0 | ALARM FREQUENCY                                     |
| 1         | 1         | 1         | 1         | Once per second                                     |
| 0         | 1         | 1         | 1         | Once per minute when seconds match                  |
| 0         | 0         | 1         | 1         | Once per hour, when minutes and seconds match       |
| 0         | 0         | 0         | 1         | Once per day, when hours, minutes and seconds match |
| 0         | 0         | 0         | 0         | When date, hours minutes and seconds match          |

#### POWER-FAIL INTERRUPT

When  $V_{CC}$  falls to the power-fail-detect point, the power-fail flag PWRF is set. If the power-fail interrupt enable bit (PWRIE) is also set, then  $\overline{\text{INT}}$  is asserted low. The power-fail interrupt occurs  $t_{WPT}$  before the bq4802Y/bq4802LY generates a reset and deselects.

#### **BATTERY-LOW WARNING**

The bq4802Y/bq4802LY checks the battery on power-up. When the battery voltage is approximately 2.1 V, the battery valid flag BVF in the flags register is set to a 0 indicating that clock and RAM data may be invalid.





6-Feb-2020

#### PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package | Pins | Package | Eco Plan                   | Lead/Ball Finish | MSL Peak Temp      | Op Temp (°C) | Device Marking | Samples |
|------------------|--------|--------------|---------|------|---------|----------------------------|------------------|--------------------|--------------|----------------|---------|
|                  | (1)    |              | Drawing |      | Qty     | (2)                        | (6)              | (3)                |              | (4/5)          |         |
| BQ4802LYDW       | ACTIVE | SOIC         | DW      | 28   | 20      | Green (RoHS<br>& no Sb/Br) | NIPDAU           | Level-1-260C-UNLIM | 0 to 70      | 4802LYDW       | Samples |
| BQ4802LYDWR      | ACTIVE | SOIC         | DW      | 28   | 1000    | Green (RoHS<br>& no Sb/Br) | NIPDAU           | Level-1-260C-UNLIM | 0 to 70      | 4802LYDW       | Samples |
| BQ4802LYDWRG4    | ACTIVE | SOIC         | DW      | 28   | 1000    | Green (RoHS<br>& no Sb/Br) | NIPDAU           | Level-1-260C-UNLIM | 0 to 70      | 4802LYDW       | Samples |
| BQ4802LYPW       | ACTIVE | TSSOP        | PW      | 28   | 50      | Green (RoHS<br>& no Sb/Br) | NIPDAU           | Level-1-260C-UNLIM | 0 to 70      | 4802LYPW       | Samples |
| BQ4802LYPWR      | ACTIVE | TSSOP        | PW      | 28   | 2000    | Green (RoHS<br>& no Sb/Br) | NIPDAU           | Level-1-260C-UNLIM | 0 to 70      | 4802LYPW       | Samples |
| BQ4802YDW        | ACTIVE | SOIC         | DW      | 28   | 20      | Green (RoHS<br>& no Sb/Br) | NIPDAU           | Level-1-260C-UNLIM | 0 to 70      | 4802YDW        | Samples |
| BQ4802YDWR       | ACTIVE | SOIC         | DW      | 28   | 1000    | Green (RoHS<br>& no Sb/Br) | NIPDAU           | Level-1-260C-UNLIM | 0 to 70      | 4802YDW        | Samples |
| BQ4802YPW        | ACTIVE | TSSOP        | PW      | 28   | 50      | Green (RoHS<br>& no Sb/Br) | NIPDAU           | Level-1-260C-UNLIM | 0 to 70      | 4802YPW        | Samples |

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



### PACKAGE OPTION ADDENDUM

6-Feb-2020

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

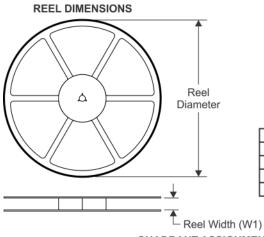
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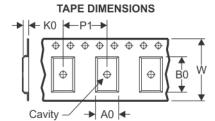
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PACKAGE MATERIALS INFORMATION

www.ti.com 20-Feb-2016

## TAPE AND REEL INFORMATION





|    | Dimension designed to accommodate the component width     |
|----|-----------------------------------------------------------|
| B0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

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|----------------------------------|------------------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|--|--|
| Device                           | Package<br>Type        | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |  |  |
| BQ4802LYDWR                      | SOIC                   | DW                 | 28 | 1000 | 330.0                    | 32.4                     | 11.35      | 18.67      | 3.1        | 16.0       | 32.0      | Q1               |  |  |
| BQ4802LYPWR                      | TSSOP                  | PW                 | 28 | 2000 | 330.0                    | 16.4                     | 6.9        | 10.2       | 1.8        | 12.0       | 16.0      | Q1               |  |  |
| BQ4802YDWR                       | SOIC                   | DW                 | 28 | 1000 | 330.0                    | 32.4                     | 11.35      | 18.67      | 3.1        | 16.0       | 32.0      | Q1               |  |  |

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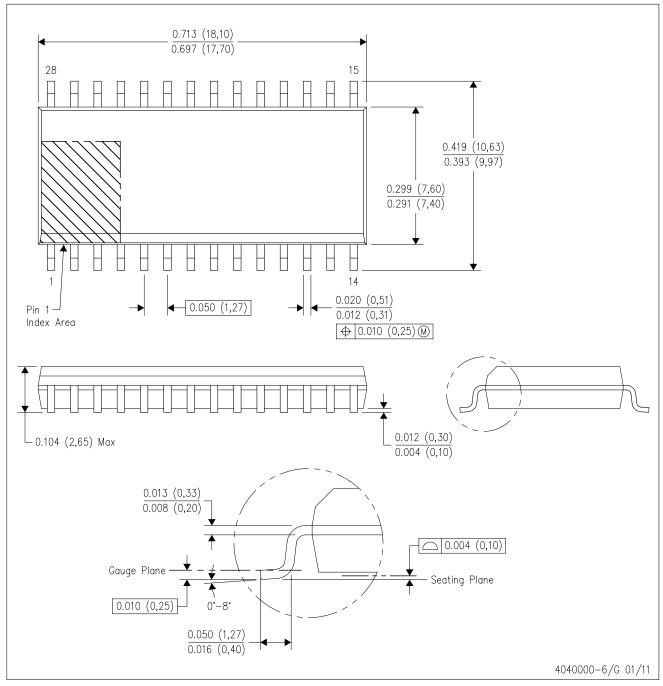


\*All dimensions are nominal

| 7 till diffrierierierie die Frierrinia |              |                              |    |      |             |            |             |  |
|----------------------------------------|--------------|------------------------------|----|------|-------------|------------|-------------|--|
| Device                                 | Package Type | Package Type Package Drawing |    | SPQ  | Length (mm) | Width (mm) | Height (mm) |  |
| BQ4802LYDWR                            | SOIC         | DW                           | 28 | 1000 | 367.0       | 367.0      | 55.0        |  |
| BQ4802LYPWR                            | TSSOP        | PW                           | 28 | 2000 | 367.0       | 367.0      | 38.0        |  |
| BQ4802YDWR                             | SOIC         | DW                           | 28 | 1000 | 367.0       | 367.0      | 55.0        |  |

DW (R-PDSO-G28)

## PLASTIC SMALL OUTLINE



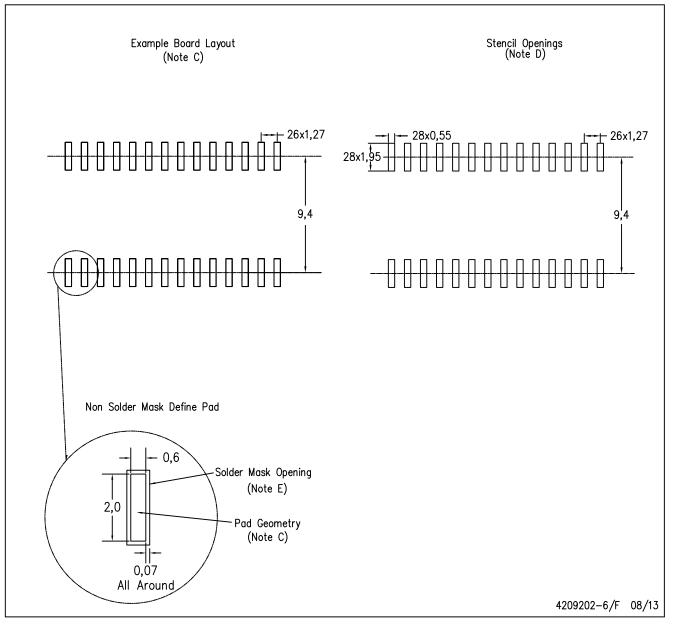
NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AE.



## DW (R-PDSO-G28)

## PLASTIC SMALL OUTLINE



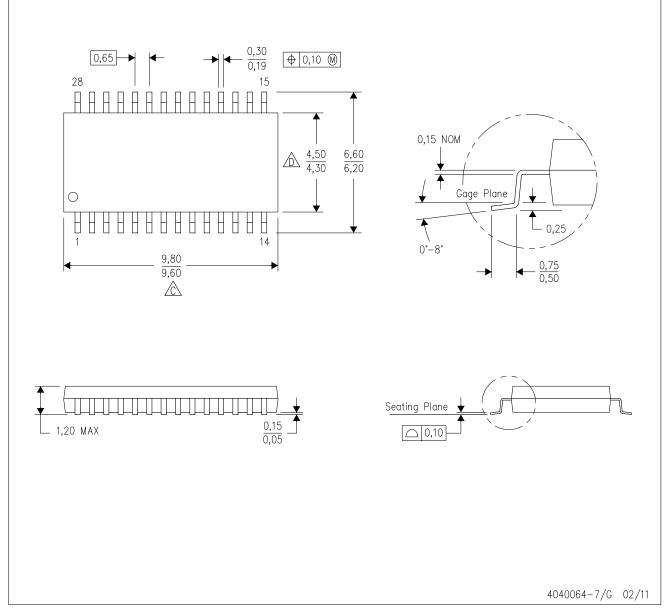
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G28)

## PLASTIC SMALL OUTLINE



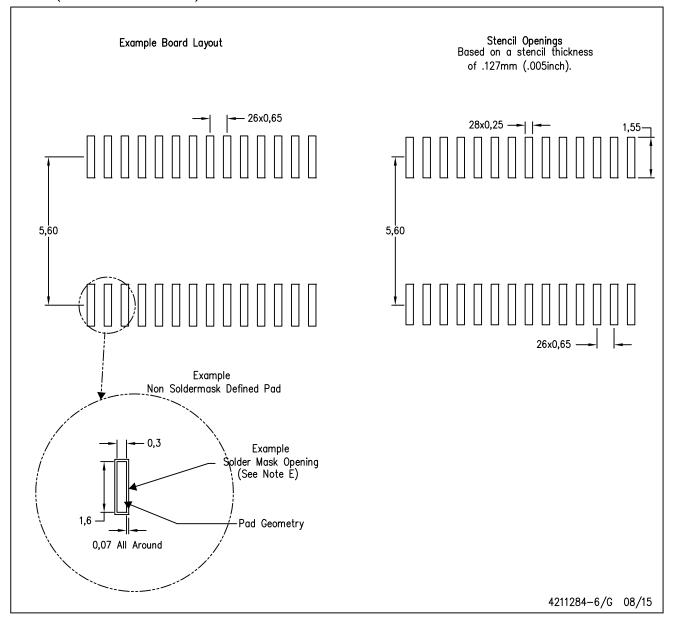
NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



## PW (R-PDSO-G28)

## PLASTIC SMALL OUTLINE



NOTES:

- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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